BC857BS

45V DUAL PNP SMALL SIGNAL SURFACE MOUNT TRANSISTOR

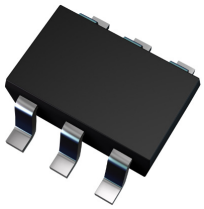
Features

- Ultra-Small Surface Mount Package
- Ideally Suited for Automated Insertion
- For switching and AF Amplifier Application
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP capable (Note 4)**

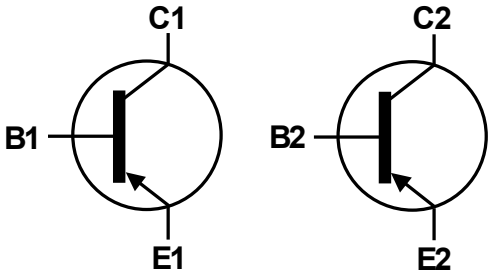
Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish — Matte Tin Finish. Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.006 grams (approximate)

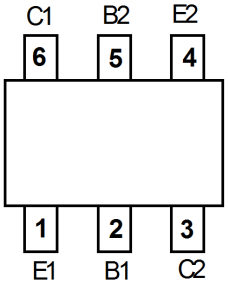
SOT363



Top View



Device Symbol



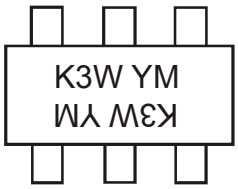
Top View
Pin-Out

Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
BC857BS-7-F	AEC-Q101	K3W	7	8	3,000
BC857BSQ-7-F	Automotive	K3W	7	8	3,000
BC857BS-13-F	AEC-Q101	K3W	13	8	10,000

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



K3W = Product Type Marking Code
YM = Date Code Marking
Y = Year (ex: A = 2013)
M = Month (ex: 9 = September)

Date Code Key

Year	2010	2011	2012	2013	2014	2015	2016	2017
Code	X	Y	Z	A	B	C	D	E

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

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Absolute Maximum Ratings (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-50	V
Collector-Emitter Voltage	V_{CEO}	-45	V
Emitter-Base Voltage	V_{EBO}	-5.0	V
Collector Current	I_C	-100	mA
Peak Collector Current	I_{CM}	-200	mA
Peak Base Current	I_{BM}	-200	mA

Thermal Characteristics (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P_D	200	mW
Thermal Resistance, Junction to Ambient Air (Note 6)	$R_{\theta JA}$	625	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C unless otherwise specified.)

Characteristic (Note 7)	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	-50	—	—	V	I_C = 100μA, I_B = 0
Collector-Emitter Breakdown Voltage	BV_{CEO}	-45	—	—	V	I_C = 10mA, I_B = 0
Emitter-Base Breakdown Voltage	BV_{EBO}	-5	—	—	V	I_E = 100μA, I_C = 0
DC Current Gain	h_{FE}	220	—	475	—	V_{CE} = -5.0V, I_C = -2.0mA
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	—	—	-100 -400	mV	I_C = -10mA, I_B = -0.5mA I_C = -100mA, I_B = -5.0mA
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	—	-700	—	mV	I_C = -10mA, I_B = -0.5mA
Base-Emitter Voltage	$V_{BE(on)}$	-580	-665	-750	mV	V_{CE} = -5.0V, I_C = -2.0mA
Collector-Cutoff Current	I_{CBO}	— —	— —	-15 -4.0	nA μA	V_{CB} = -30V V_{CB} = -30V, T_A = +150°C
Emitter Cutoff Current	I_{EBO}	—	—	-100	nA	V_{EB} = -5.0V, I_C = 0
Gain Bandwidth Product	f_T	100	—	—	MHz	V_{CE} = -5.0V, I_C = -10mA, f = 100MHz
Collector-Base Capacitance	C_{CBO}	—	2	3	pF	V_{CB} = -10V, f = 1.0MHz
Emitter-Base Capacitance	C_{EBO}	—	11	—	pF	V_{EB} = -0.5V, f = 1.0MHz

Notes: 6. For the device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
7. Short duration pulse test used to minimize self-heating effect.

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Typical Electrical Characteristics (@T_A = +25°C unless otherwise specified.)

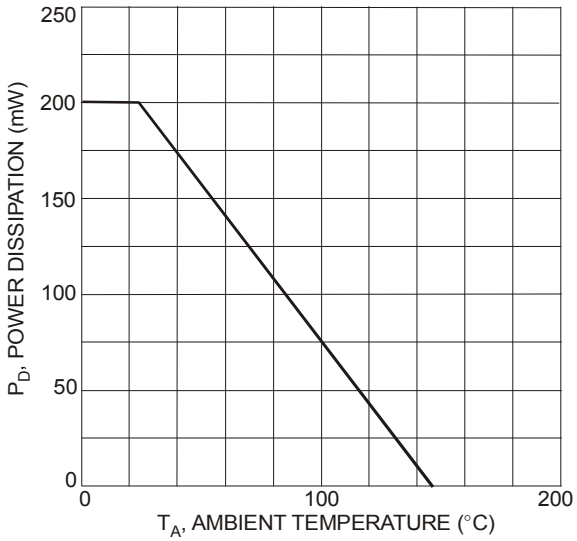

Fig. 1 Power Dissipation vs. Ambient Temperature

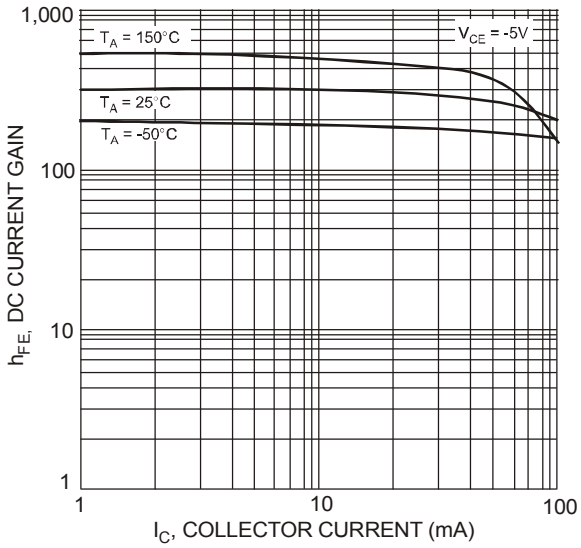

Fig. 2 Typical DC Current Gain vs. Collector Current

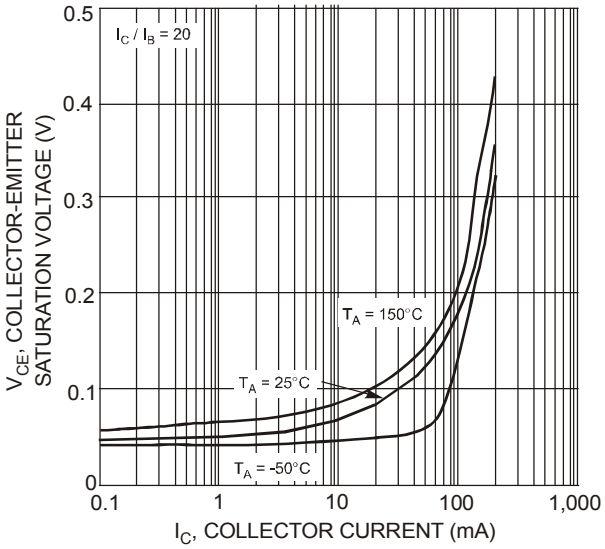

Fig. 3 Typical Collector-Emitter Saturation Voltage vs. Collector Current

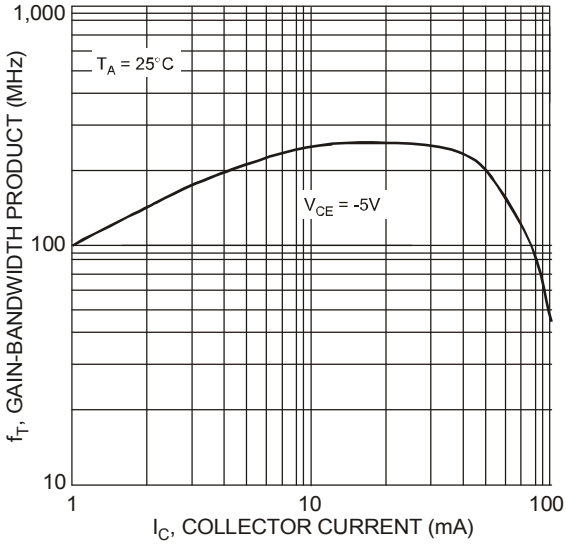

Fig. 4 Typical Gain-Bandwidth Product vs. Collector Current

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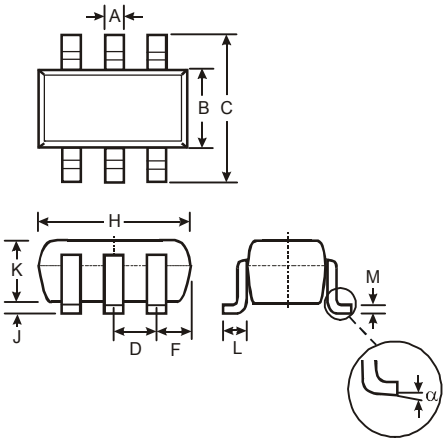
Package Outline Dimensions

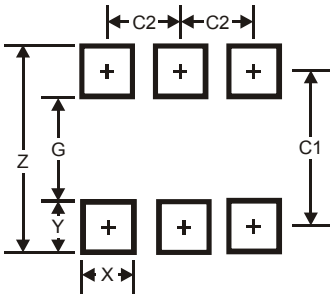
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT363			
Dim	**Min**	**Max**	**Typ**
A	0.10	0.30	0.25
B	1.15	1.35	1.30
C	2.00	2.20	2.10
D	0.65 Typ		
F	0.40	0.45	0.425
H	1.80	2.20	2.15
J	0	0.10	0.05
K	0.90	1.00	1.00
L	0.25	0.40	0.30
M	0.10	0.22	0.11
α	0°	8°	-
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.5
G	1.3
X	0.42
Y	0.6
C1	1.9
C2	0.65

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